

MiniSKiiP® 3

3-phase bridge rectifier + brake chopper + 3-phase bridge inverter SKIIP 36NAB126V10

Features

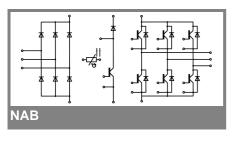
- Fast Trench IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

Typical Applications*

- Inverter up to 36 kVA
- Typical motor power 18,5 kW

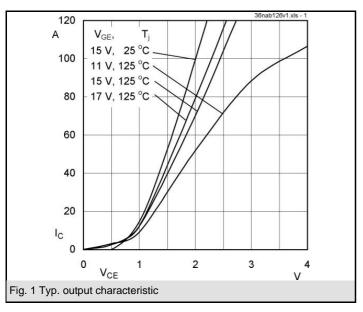
Remarks

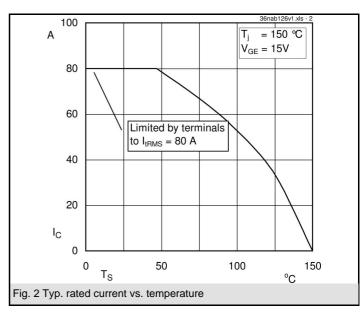
• V_{CEsat} , V_F = chip level value

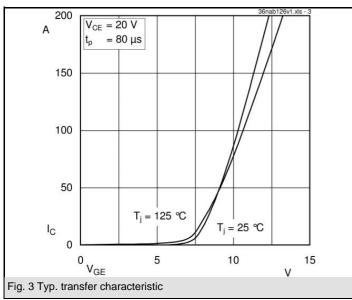


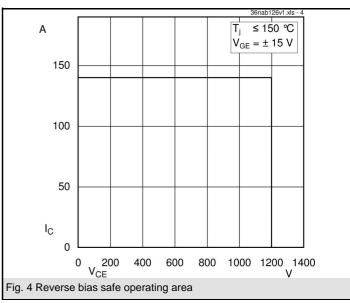
Absolute Maximum Ratings T _s = 25 °C, unless otherwise specified							
Symbol	Conditions	Values	Units				
IGBT - Inverter, Chopper							
V_{CES}		1200	V				
I _C	T _s = 25 (70) °C	88 (66)	Α				
I _{CRM}		140	Α				
V_{GES}		± 20	V				
T _j		- 40 + 150	°C				
Diode - Inverter, Chopper							
I _F	T _s = 25 (70) °C	91 (68)	Α				
I _{FRM}		140	Α				
T _j		- 40 + 150	°C				
Diode - Rectifier							
V_{RRM}		1600	V				
I _F	T _s = 70 °C	67	Α				
I _{FSM}	t _p = 10 ms, sin 180 °, T _i = 25 °C	850	Α				
i²t	$t_p = 10 \text{ ms, sin } 180 ^\circ, T_i = 25 ^\circ\text{C}$	3600	A²s				
T_j	,	- 40 + 150	°C				
Module	·	·	•				
I _{tRMS}	per power terminal (20 A / spring)	80	Α				
T _{stg}		- 40 + 125	°C				
V _{isol}	AC, 1 min.	2500	V				

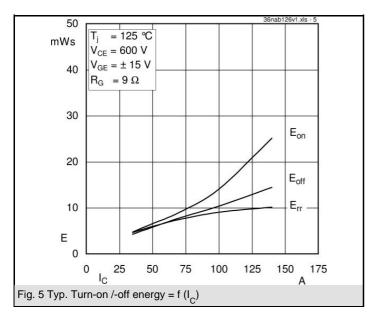
Character	ristics	T _s = 25 °C,	T _s = 25 °C, unless otherwise specified					
Symbol	Conditions	min.	typ.	max.	Units			
IGBT - Inverter, Chopper								
V _{CEsat} V _{GE(th)} V _{CE(TO)} r _T C _{ies}	$I_{Cnom} = 70 \text{ A}, T_j = 25 (125) ^{\circ}\text{C}$ $V_{GE} = V_{CE}, I_C = 3 \text{ mA}$ $T_j = 25 (125) ^{\circ}\text{C}$ $T_j = 25 (125) ^{\circ}\text{C}$ $V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$	5	1,7 (2) 5,8 1 (0,9) 10 (16) 4,8	2,1 (2,4) 6,5 1,2 (1,1) 13 (19)	V V V mΩ nF			
C _{oes} C _{res} R _{th(j-s)}	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ $V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$ per IGBT		1 0,6 0,5		nF nF K/W			
$t_{d(on)}$ t_{r} $t_{d(off)}$ t_{f} E_{on} E_{off}	under following conditions $\begin{aligned} &V_{CC} = 600 \text{ V}, V_{GE} = \pm 15 \text{ V} \\ &I_{Cnom} = 70 \text{ A}, T_j = 125 ^{\circ}\text{C} \\ &R_{Gon} = R_{Goff} = 9 \Omega \\ &\text{inductive load} \end{aligned}$		80 25 390 90 9 7,7		ns ns ns ns mJ mJ			
Diode - Inverter, Chopper								
$V_{F} = V_{EC}$ $V_{(TO)}$ r_{T} $R_{th(j-s)}$ I_{RRM} Q_{rr} E_{rr}	$\begin{aligned} & I_{Fnom} = 70 \text{ A, } T_j = 25 \text{ (125) °C} \\ & T_j = 25 \text{ (125) °C} \\ & T_j = 25 \text{ (125) °C} \\ & per \text{ diode} \\ & under \text{ following conditions} \\ & I_{Fnom} = 70 \text{ A, } V_R = 600 \text{ V} \\ & V_{GE} = 0 \text{ V, } T_j = 125 \text{ °C} \\ & di_F/dt = 2000 \text{ A/µs} \end{aligned}$		1,5 (1,5) 1 (0,8) 7,1 (10) 0,7 77 18 7,5	1,7 (1,7) 1,1 (0,9) 8,6 (11)	V V mΩ K/W A μC mJ			
Diode - Rectifier								
$V_{\text{F}} \\ V_{\text{(TO)}} \\ r_{\text{T}} \\ R_{\text{th(j-s)}}$	$I_{\rm Fnom}$ = 40 A, $T_{\rm j}$ = 25 °C $T_{\rm j}$ = 125 °C $T_{\rm j}$ = 125 °C per diode		1,1 0,8 9 0,85		V V mΩ K/W			
-	ure Sensor	1			,			
R _{ts}	3 %, T _r = 25 (100) °C		1000(1670)		Ω			
Mechanic w			95		g			
M_s	Mounting torque	2		2,5	Nm			

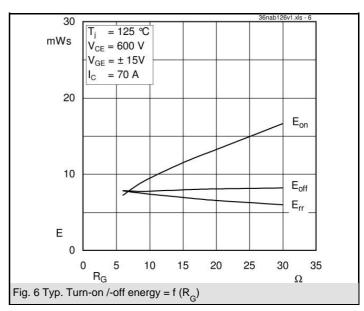


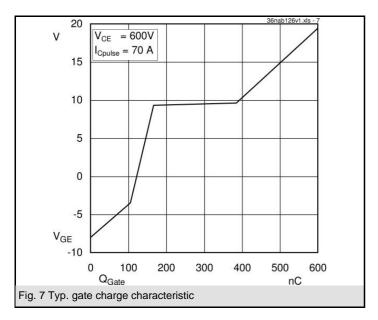


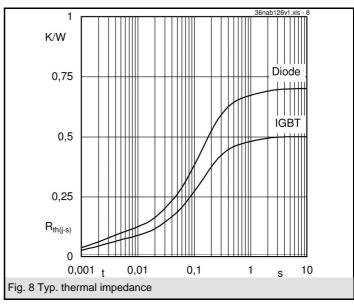


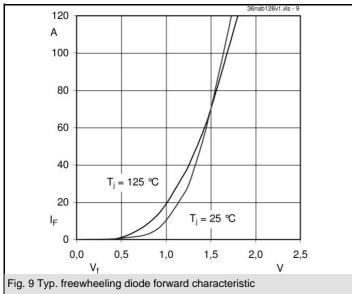


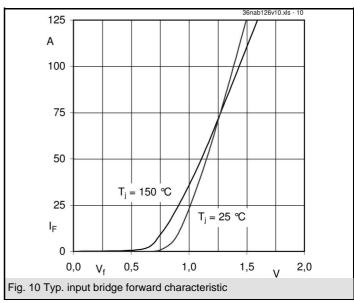




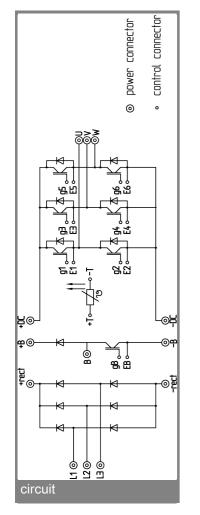


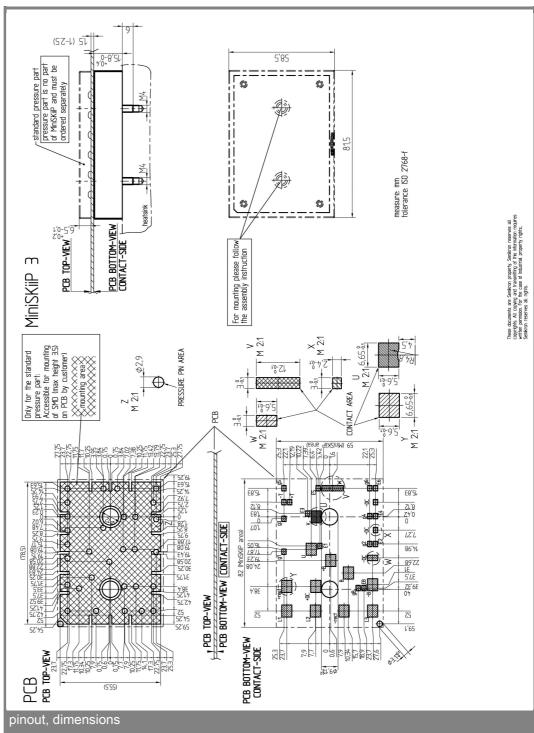






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This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

^{*} The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.